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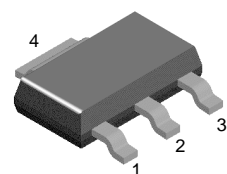
[sales@integrated-circuit.com](mailto:sales@integrated-circuit.com)



## NZT6727

### PNP General Purpose Amplifier

- This device is designed for general purpose medium power amplifiers and switches requiring collector currents to 1.0A.
- Sourced from process 77.



SOT-223

1. Base 2. Collector 3. Emitter

### Absolute Maximum Ratings\* $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CEO}$	Collector-Emitter Voltage	-40	V
$V_{CBO}$	Collector-Base Voltage	-50	V
$V_{EBO}$	Emitter-Base Voltage	-5.0	V
$I_C$	Collector Current - Continuous	-1.5	A
$T_J, T_{STG}$	Operating and Storage Junction Temperature Range	- 55 ~ 150	$^\circ\text{C}$

\* These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

- These ratings are based on a maximum junction temperature of 150 degrees C.
- These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
<b>Off Characteristics</b>					
$V_{(BR)CEO}$	Collector-Emitter Sustaining Voltage *	$I_C = -10\text{mA}, I_B = 0$	-40		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = -1.0\text{mA}, I_E = 0$	-50		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = -100\mu\text{A}, I_C = 0$	-5.0		V
$I_{CBO}$	Collector Cutoff Current	$V_{CB} = -50\text{V}, I_E = 0$		-0.1	$\mu\text{A}$
$I_{EBO}$	Emitter Cut-off Current	$V_{EB} = -5.0\text{V}, I_C = 0$		-0.1	$\mu\text{A}$
<b>On Characteristics</b>					
$h_{FE}$	DC Current Gain	$I_C = -10\text{mA}, V_{CE} = -1.0\text{V}$ $I_C = -100\text{mA}, V_{CE} = -1.0$ $I_C = -1.0\text{A}, V_{CE} = -1.0\text{V}$	55 60 50	250	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = -1.0\text{A}, I_B = -100\text{mA}$		-0.5	V
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C = -1.0\text{A}, V_{CE} = -1.0\text{V}$		-1.2	V
<b>Small Signal Characteristics</b>					
$h_{fe}$	Small Signal current Gain	$I_C = -50\text{mA}, V_{CE} = -10\text{V}, f = 20\text{MHz}$	2.5	25	
$C_{cb}$	Collector-Base Capacitance	$V_{CB} = -10\text{V}, I_E = 0, f = 1.0\text{MHz}$		30	pF

\* Pulse Test: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle  $\leq 1.0\%$

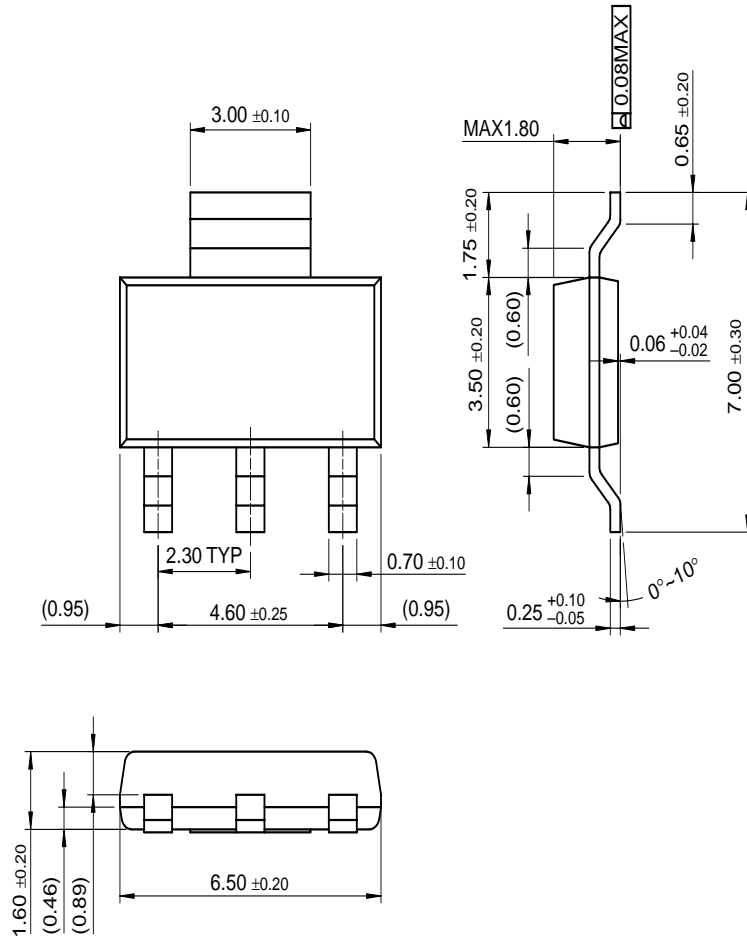
### Thermal Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Max.	Units
$P_D$	Total Device Dissipation Derate above $25^\circ\text{C}$	1.0 8.0	W $\text{mW}/^\circ\text{C}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	125	$^\circ\text{C}/\text{W}$

\* Device mounted on FR-4PCB  $36\text{mm} \times 18\text{mm} \times 1.5\text{mm}$ ; mounting pad for the collector lead min.  $6\text{cm}^2$ .

Package Dimensions

SOT-223



Dimensions in Millimeters

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